

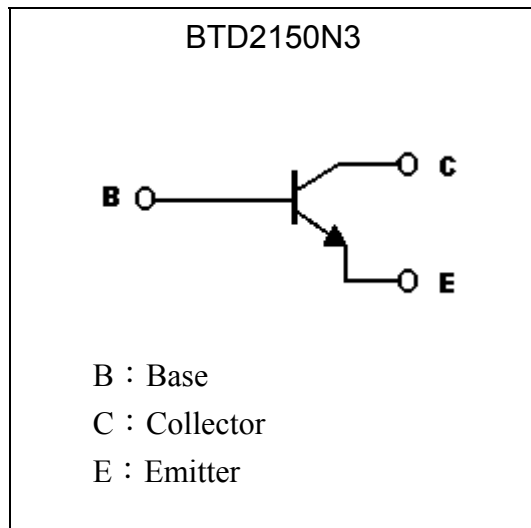
Low $V_{CE(sat)}$ NPN Epitaxial Planar Transistor
BTD2150N3

BV_{CEO}	50V
I_C	4A
$R_{CE(SAT)}$ typ.	90m Ω

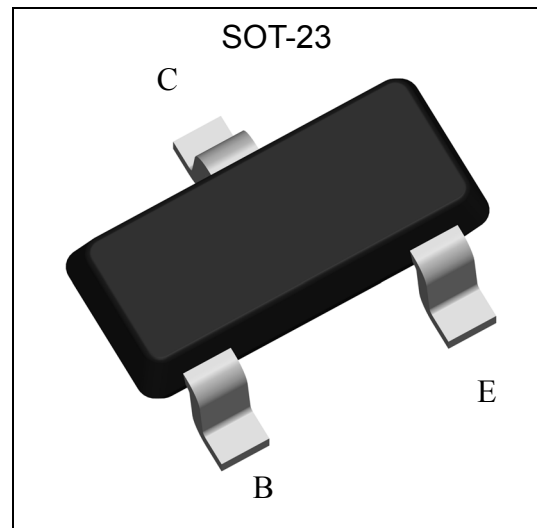
Features

- Low $V_{CE(sat)}$, typically 0.18V at $I_C / I_B = 2A / 0.1A$
- Excellent current gain characteristics
- Complementary to BTB1424N3
- Pb-free lead plating and halogen-free package

Symbol

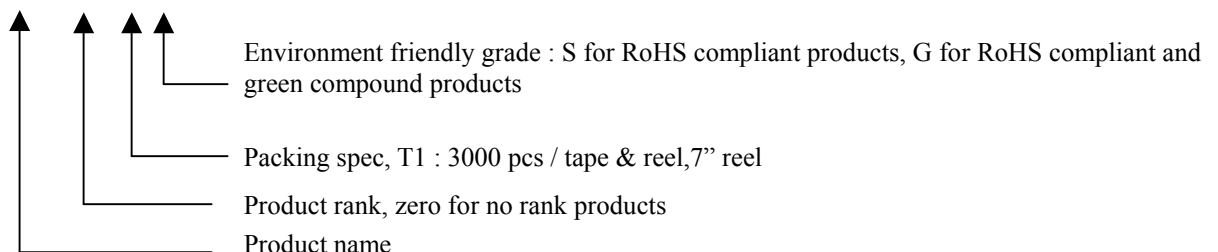


Outline



Ordering Information

Device	Package	Shipping
BTD2150N3-X-T1-G	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / tape & reel





Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CB0}	80	V
Collector-Emitter Voltage	V _{CE0}	50	
Emitter-Base Voltage	V _{EBO}	6	
Collector Current (DC)	I _C	4	A
Collector Current (Pulse)	I _{CP}	7 (Note 1)	
Power Dissipation	P _D	225	mW
		660 (Note 2)	
Thermal Resistance, Junction to Ambient	R _{θJA}	556	°C/W
		190	
Operating Junction and Storage Temperature Range	T _j ; T _{stg}	-55~+150	°C

Note : 1. Single Pulse Pw ≤ 350μs, Duty ≤ 2%.

2. Device mounted on an FR-4 PCB, single sided copper, tin plated, mounting pad for collector 1cm².

Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CB0}	80	-	-	V	I _C =100μA, I _E =0
BV _{CE0}	50	-	-	V	I _C =1mA, I _B =0
BV _{EBO}	6	-	-	V	I _E =50μA, I _C =0
I _{CB0}	-	-	100	nA	V _{CB} =80V, I _E =0
I _{EBO}	-	-	100	nA	V _{EB} =6V, I _C =0
*V _{CE(sat)}	-	40	100	mV	I _C =400mA, I _B =20mA
*V _{CE(sat)}	-	160	220	mV	I _C =1A, I _B =10mA
*V _{CE(sat)}	-	180	320	mV	I _C =2A, I _B =100mA
*R _{CE(sat)}	-	90	160	mΩ	I _C =2A, I _B =100mA
*V _{BE(sat)}	-	0.94	1.3	V	I _C =2A, I _B =200mA
*h _{FE1}	200	-	-	-	V _{CE} =2V, I _C =100mA
*h _{FE2}	270	-	820	-	V _{CE} =2V, I _C =500mA
*h _{FE3}	100	-	-	-	V _{CE} =2V, I _C =1A
f _T	-	175	-	MHz	V _{CE} =1V, I _C =0.1A, f=100MHz
Cob	-	14	-	pF	V _{CB} =10V, f=1MHz

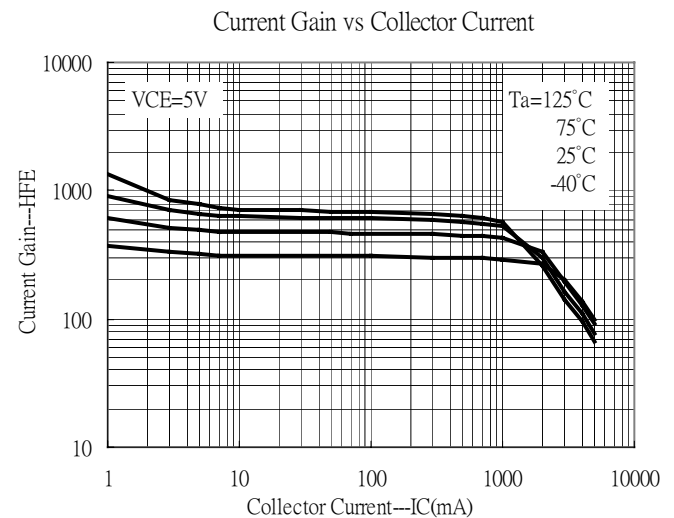
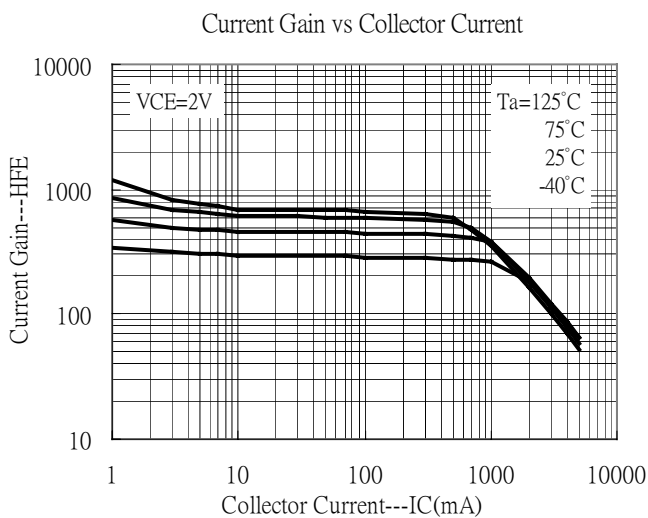
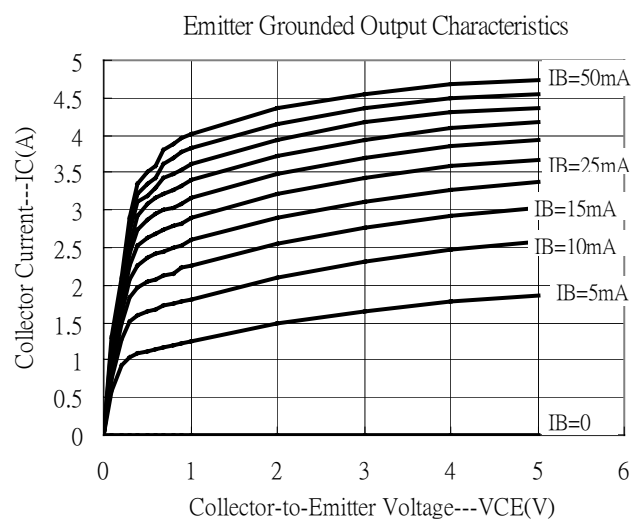
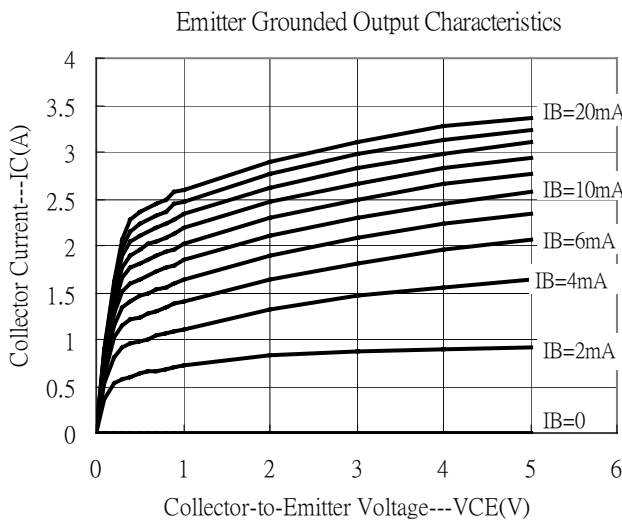
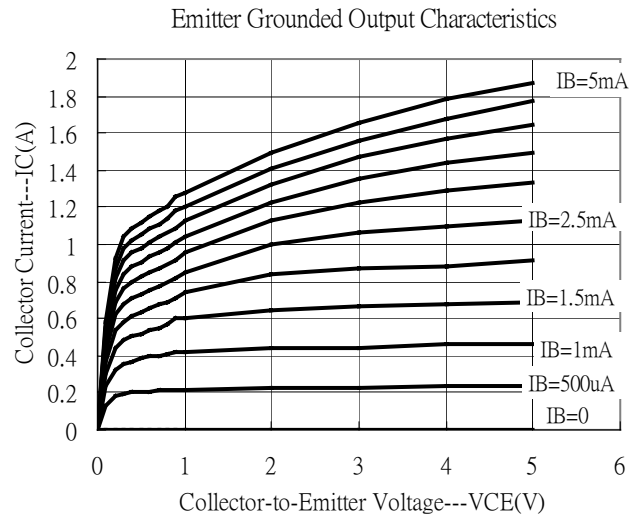
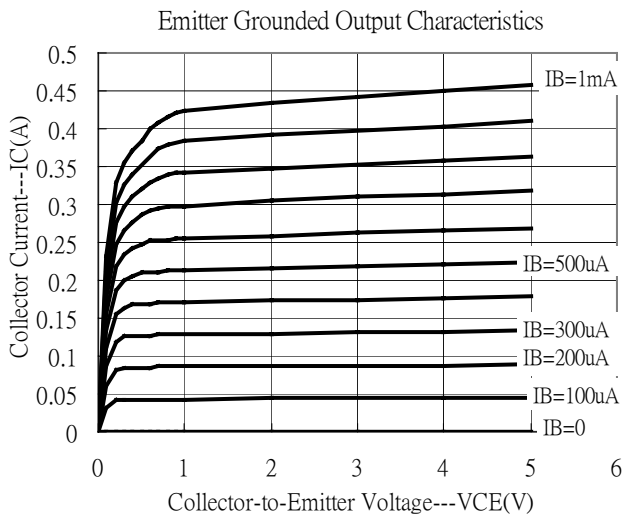
*Pulse Test : Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

Classification Of hFE 2

Rank	S	T
Range	270~560	390~820

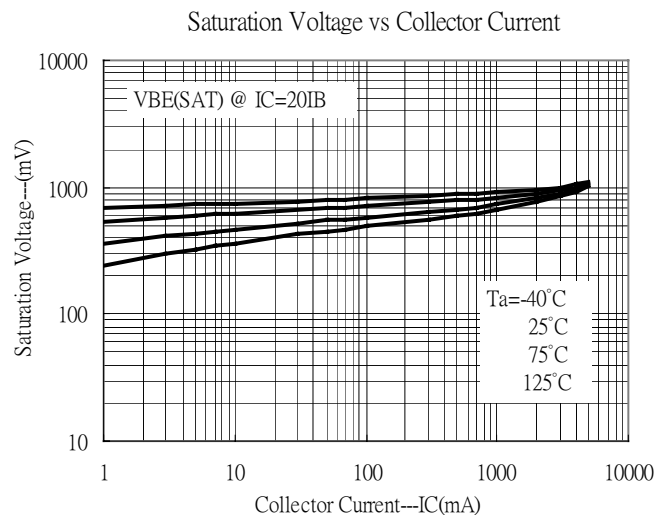
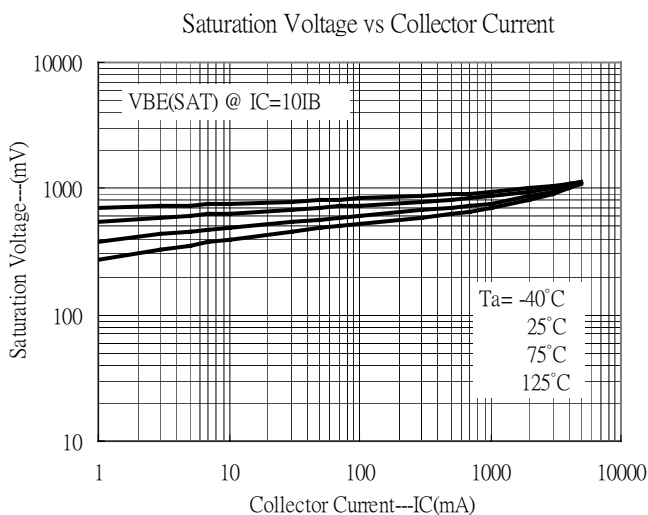
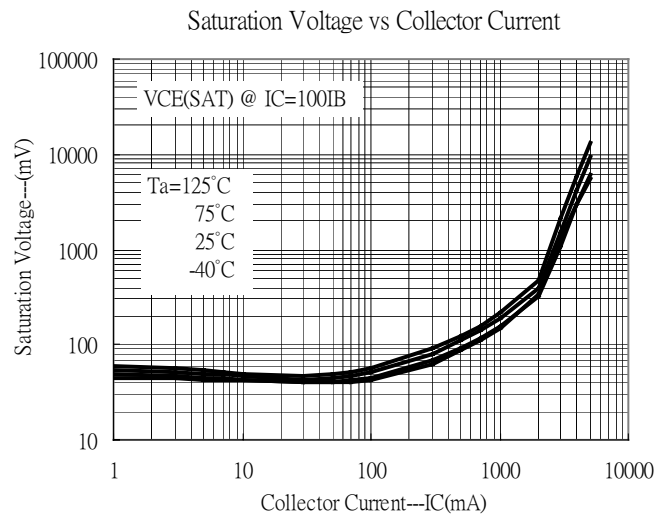
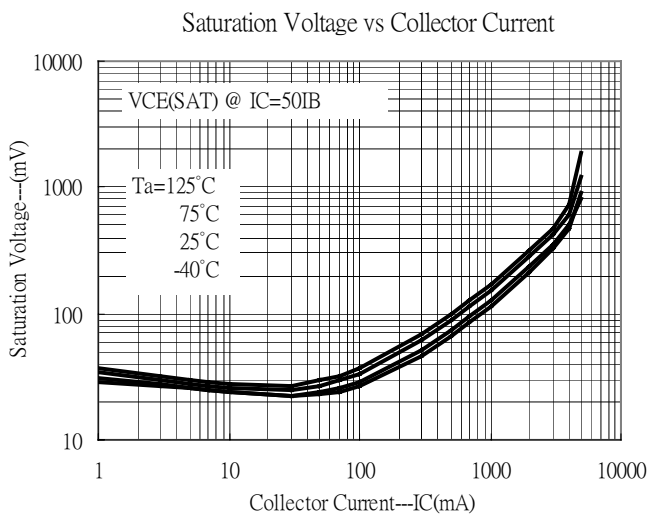
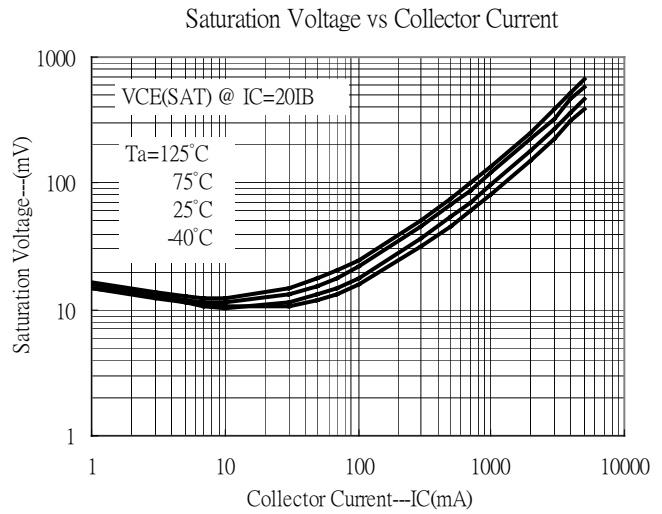
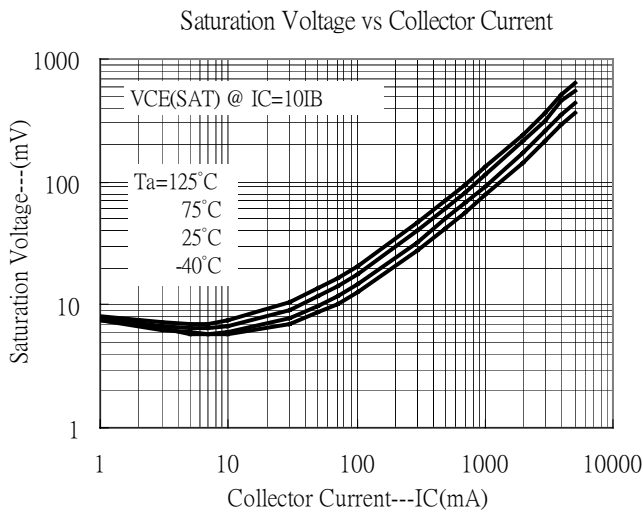


Typical Characteristics





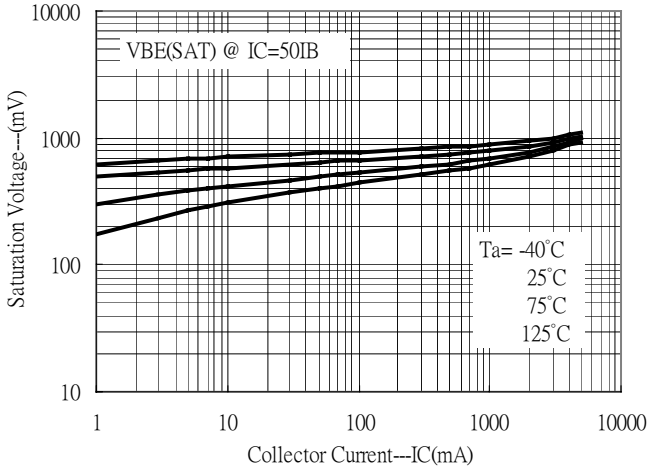
Typical Characteristics(Cont.)



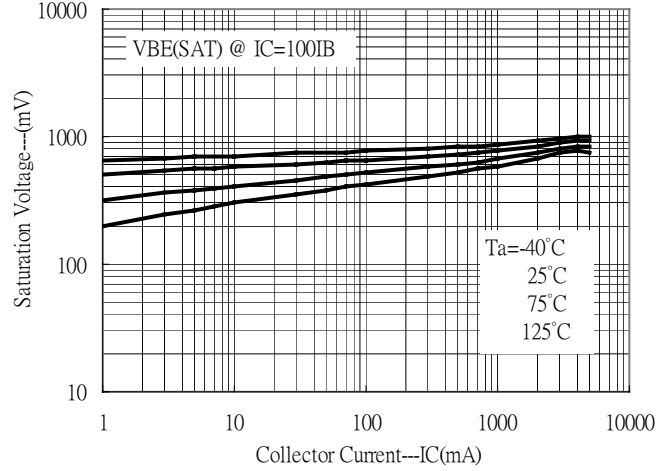


Typical Characteristics(Cont.)

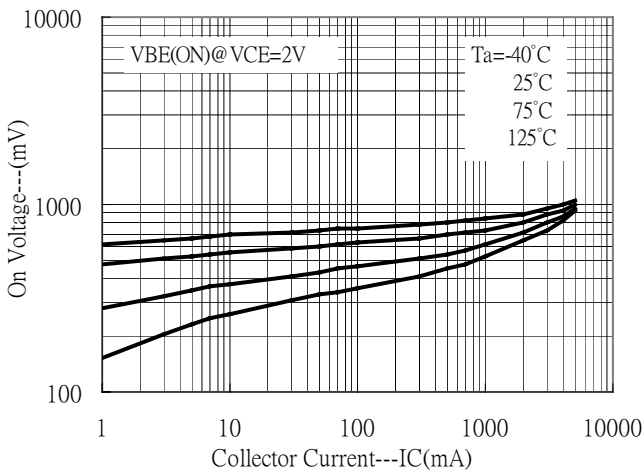
Saturation Voltage vs Collector Current



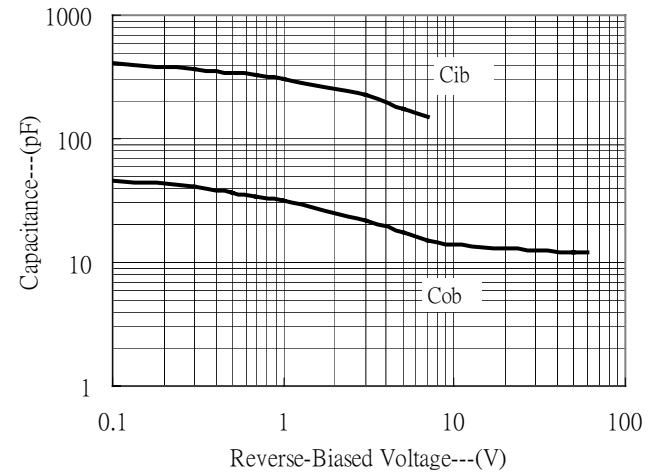
Saturation Voltage vs Collector Current



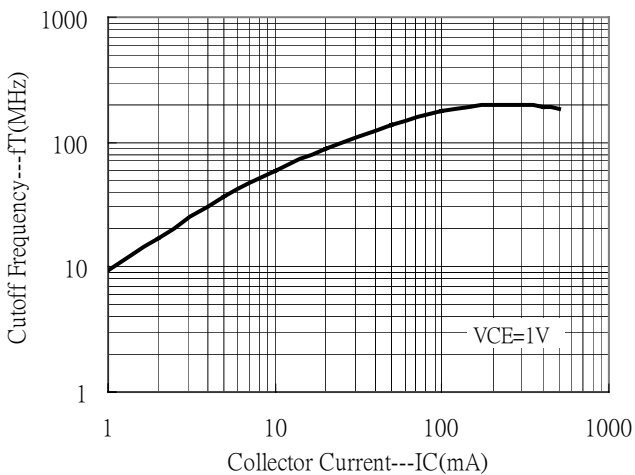
On Voltage vs Collector Current



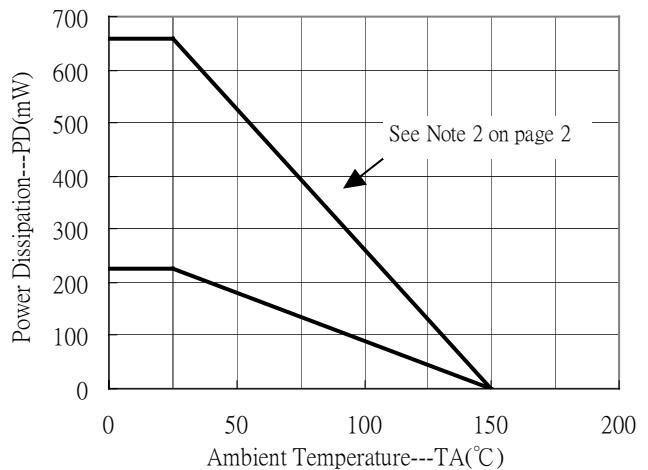
Capacitance vs Reverse-Biased Voltage



Cutoff frequency vs Collector Current

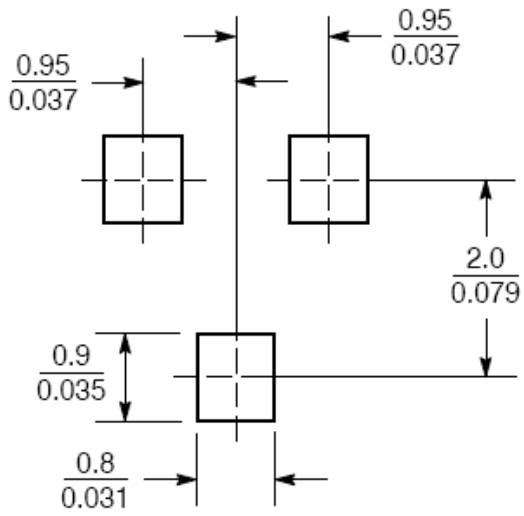


Power Derating Curve



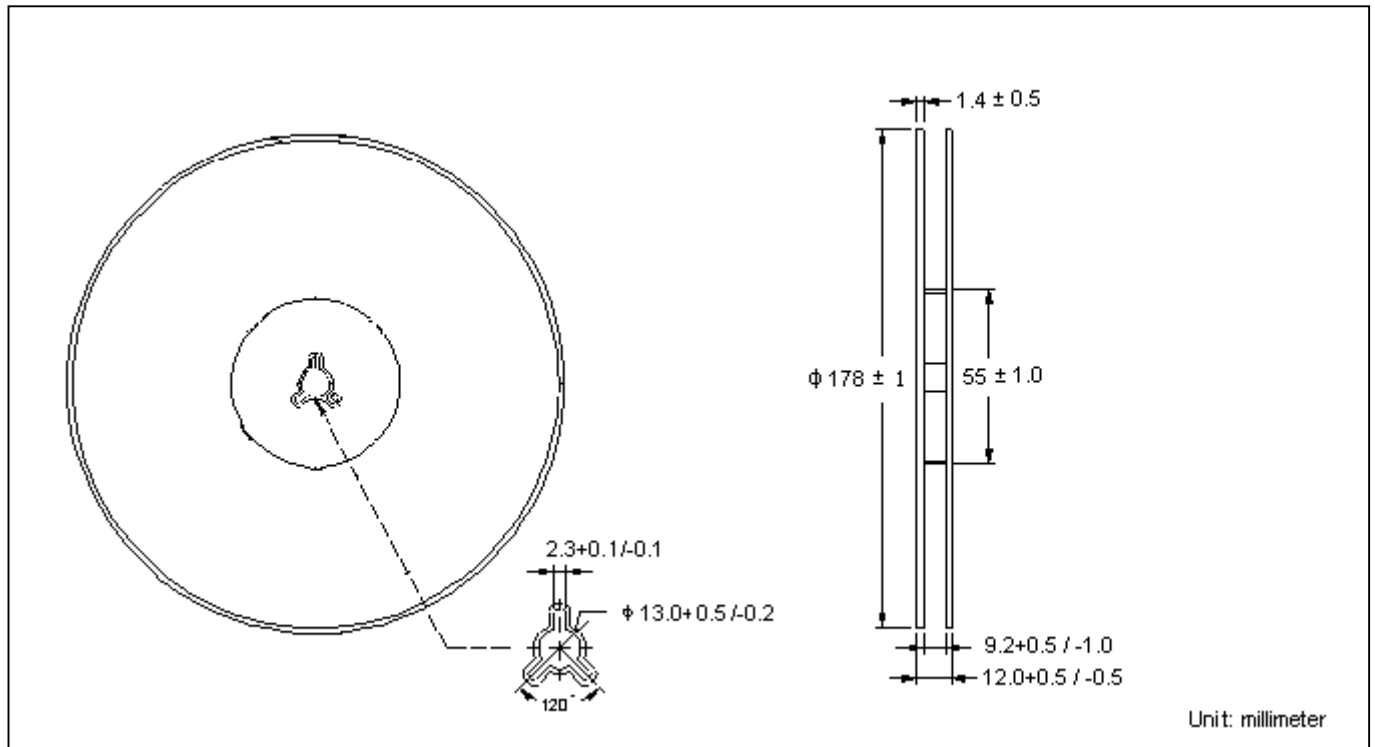


Recommended Soldering Footprint

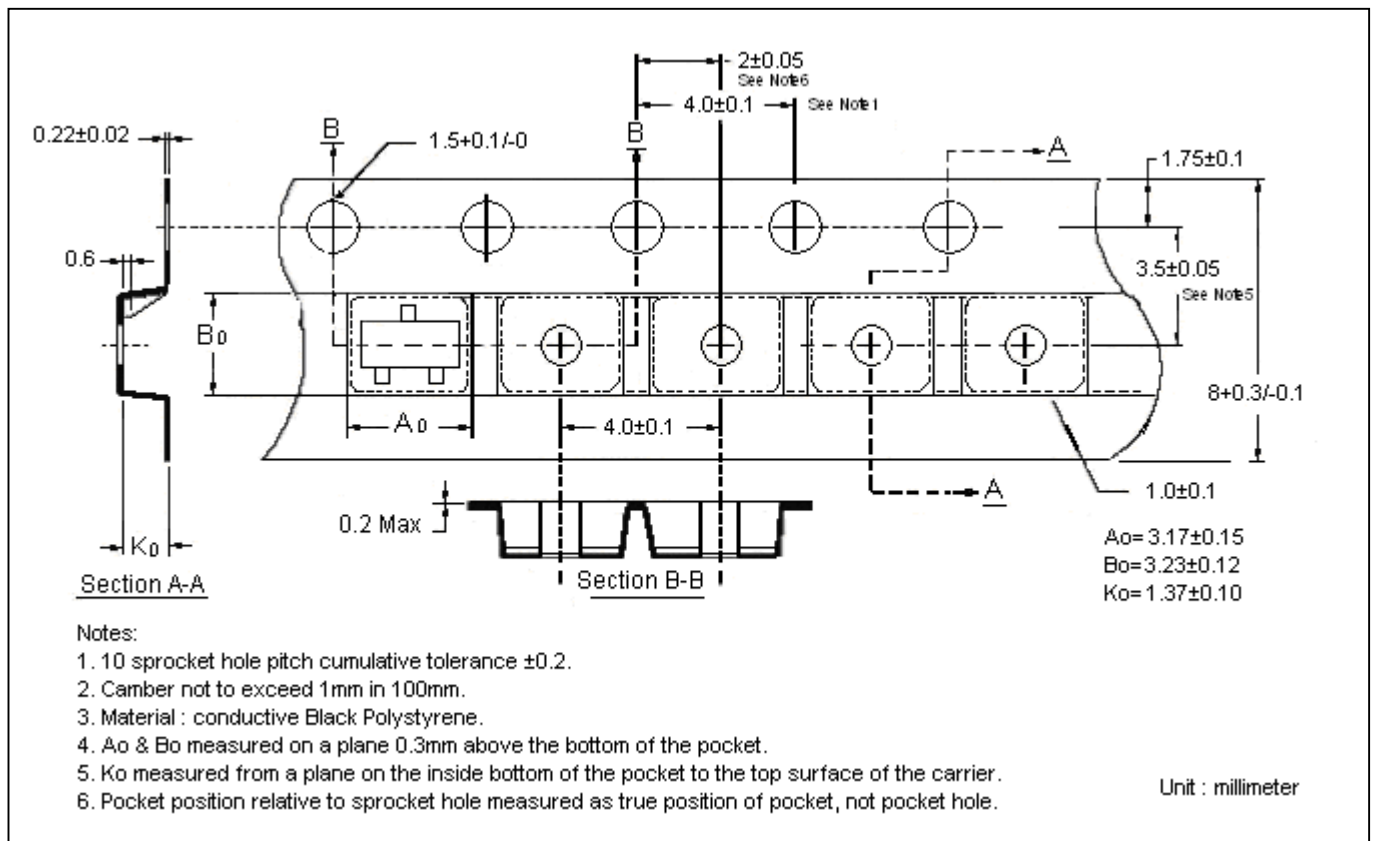


Unit : $\frac{\text{mm}}{\text{inches}}$

Reel Dimension

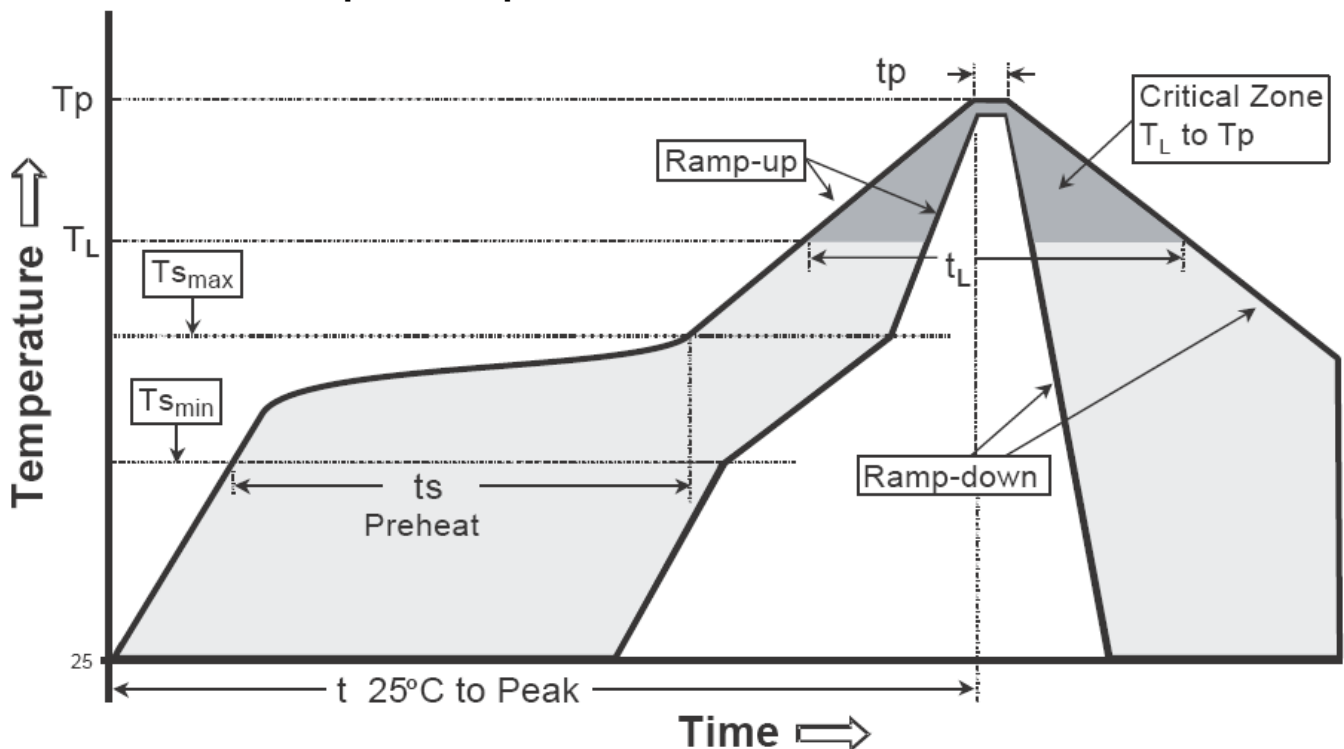


Carrier Tape Dimension



Recommended wave soldering condition

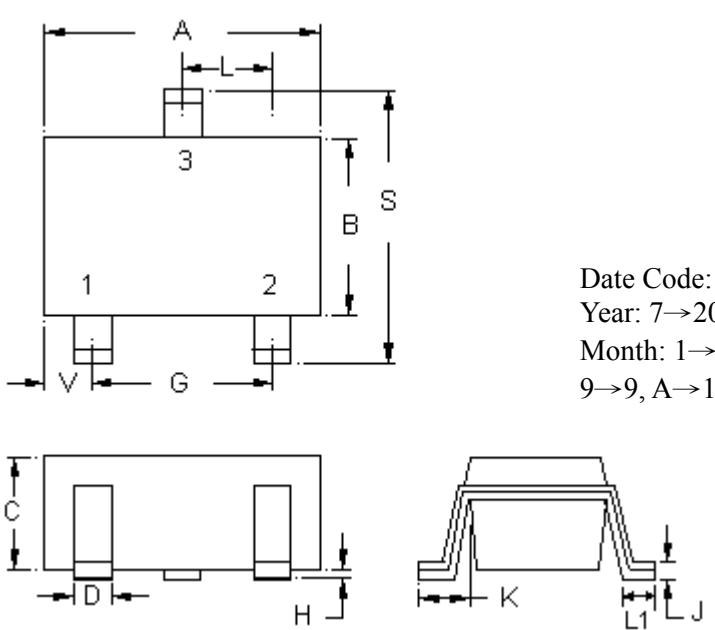
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T _{s min})	100°C	150°C
-Temperature Max(T _{s max})	150°C	200°C
-Time(ts _{min} to ts _{max})	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T _L)	183°C	217°C
- Time (t _L)	60-150 seconds	60-150 seconds
Peak Temperature(T _p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

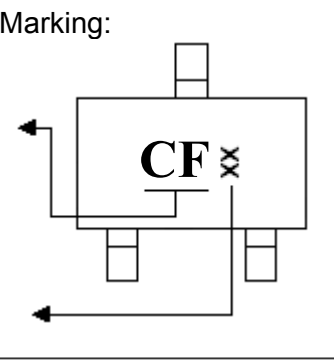
Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-23 Dimension



The diagram shows three views of the SOT-23 package: a top view with dimensions A, B, C, G, H, L, S, V; a side view with dimensions C, D, H, J; and a perspective view with dimensions K, L1, L2, J. The top view also labels pins 1, 2, and 3.

Marking:



The marking diagram shows a rectangular package with a central square containing the characters 'CF' followed by a small 'x' symbol. Arrows point to the top and bottom leads.

Product Code

Date Code: Year+Month
 Year: 7→2017, 8→2018
 Month: 1→1, 2→2, . . .
 9→9, A→10, B→11, C→12

3-Lead SOT-23 Plastic Surface Mounted Package
 CYStek Package Code: N3

Style : Pin 1.Base 2.Emitter 3.Collector

*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0032	0.0079	0.08	0.20
B	0.0472	0.0669	1.20	1.70	K	0.0118	0.0266	0.30	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1161	2.10	2.95
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0000	0.0040	0.00	0.10	L1	0.0118	0.0197	0.30	0.50

- Notes:**
- Controlling dimension: millimeters.
 - Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 - If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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